

Vishay Siliconix

N-Channel 100-V (D-S) MOSFET

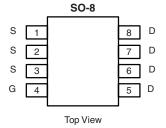
PRODUCT SUMMARY				
V _{DS} (V)	R _{DS(on)} (Ω)	I _D (A)		
100	0.025 at V _{GS} = 10 V	7.9		
	0.028 at V _{GS} = 6.0 V	7.5		

FEATURES

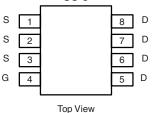
- Halogen-free According to IEC 61249-2-21 Definition
- TrenchFET[®] Power MOSFETs •
- 175 °C Maximum Junction Temperature
- **PWM Optimized**
- Compliant to RoHS Directive 2002/95/EC



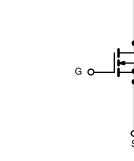
Available



Ordering Information: Si4486EY-T1-E3 (Lead (Pb)-free)



Si4486EY-T1-GE3 (Lead (Pb)-free and Halogen-free)



N-Channel MOSFET

D

ABSOLUTE MAXIMUM RATINGS $T_A = 25 \degree C$, unless otherwise noted							
Parameter		Symbol	10 s	Steady State	Unit		
Drain-Source Voltage		V _{DS}	100		V		
Gate-Source Voltage		V _{GS}	± 20				
Continuous Drain Current (T 175 °C)a	T _A = 25 °C	– I _D	7.9	5.4			
Continuous Drain Current (T _J = 175 °C) ^a	T _A = 85 °C		6.1	4.2	А		
Pulsed Drain Current		I _{DM}	40		A		
Avalanche Current	L = 0.1 mH	I _{AR}	30 45				
Repetitive Avalanche Energy (Duty Cycle \leq 1 %)		E _{AR}			mJ		
Continuous Source Current (Diode Conduction) ^a		۱ _S	3.1	1.5	А		
	T _A = 25 °C	Р	3.8	1.8	W		
Maximum Power Dissipation ^a	T _A = 85 °C	P _D	2.3	1.1	vv		
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 175		°C		

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
	t ≤ 10 s	- R _{thJA}	33	40	°C/W
Maximum Junction-to-Ambient ^a	Steady State		70	85	
Maximum Junction-to-Foot (Drain)	Steady State	R _{thJF}	17	21	

Notes:

a. Surface Mounted on 1" x 1" FR4 board.

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SPECIFICATIONS $T_J = 25 \text{ °C}$, unless otherwise noted								
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit		
Static								
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = 250 \ \mu A$	2			V		
Gate-Body Leakage	I _{GSS}				± 100	nA		
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = 80 V, V_{GS} = 0 V$			1	μA		
		$V_{DS} = 80 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 85 ^{\circ}\text{C}$			20			
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 5$ V, $V_{GS} = 10$ V	40			А		
Drain-Source On-State Resistance ^a	R _{DS(on)}	V_{GS} = 10 V, I _D = 7.9 A		0.021	0.025	Ω		
		$V_{GS} = 6.0 \text{ V}, \text{ I}_{D} = 7.5 \text{ A}$		0.023	0.028			
Forward Transconductance ^a	9 _{fs}	V _{DS} = 15 V, I _D = 7.9 A		35		S		
Diode Forward Voltage ^a	V _{SD}	$I_{\rm S} = 3.1$ A, $V_{\rm GS} = 0$ V		0.8	1.2	V		
Dynamic ^b				•				
Total Gate Charge	Qg			36	44			
Gate-Source Charge	Q _{gs}	$V_{DS} = 50 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 7.9 \text{ A}$		10		nC		
Gate-Drain Charge	Q _{gd}			8.6				
Gate Resistance	Rg		0.5	1.27	2.2	Ω		
Turn-On Delay Time	t _{d(on)}			20	40			
Rise Time	t _r	V_{DD} = 50 V, R_L = 50 Ω		10	20			
Turn-Off Delay Time	t _{d(off)}	$I_D \cong$ 1 A, V_{GEN} = 10 V, R_g = 6 Ω		46	90	ns		
Fall Time	t _f			26	50]		
Source-Drain Reverse Recovery Time	t _{rr}	I _F = 3.1 A, dl/dt = 100 A/µs		50	80			

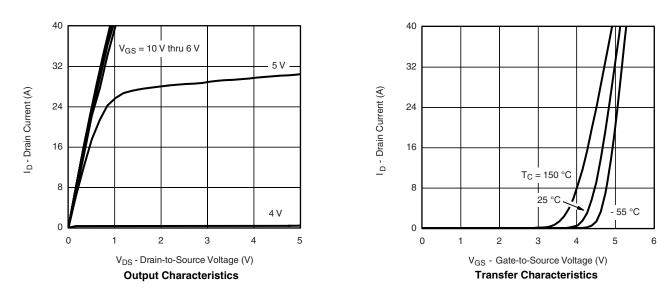
Notes:

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



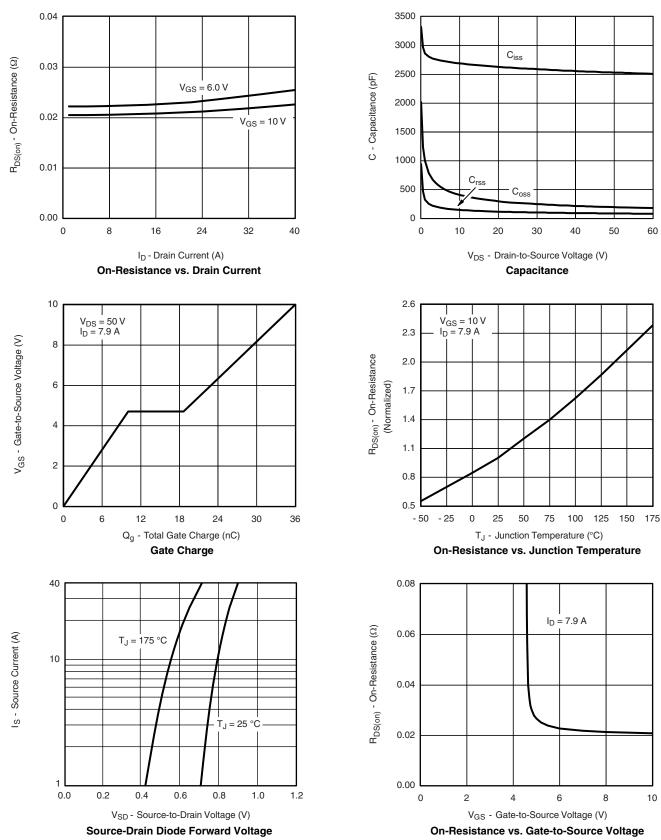
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Si4486EY

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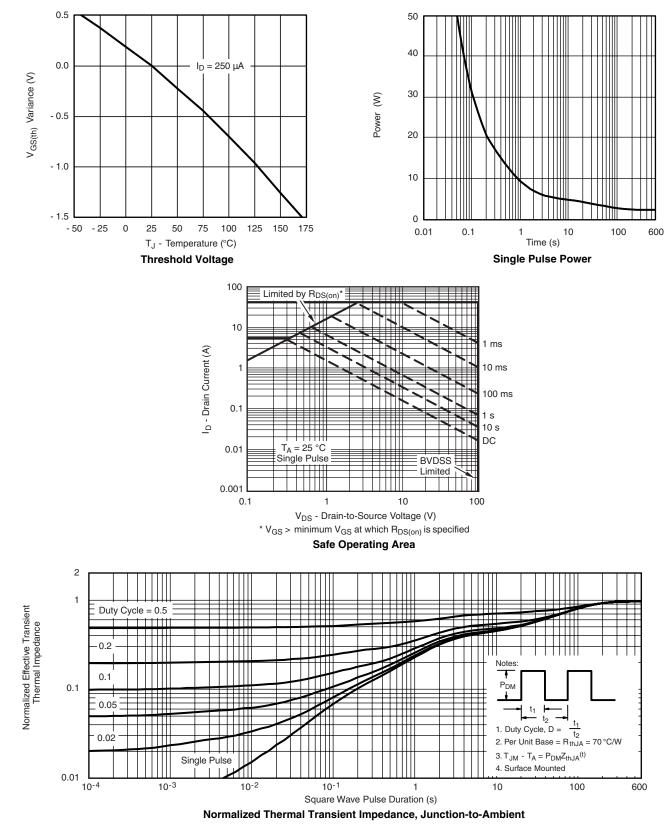
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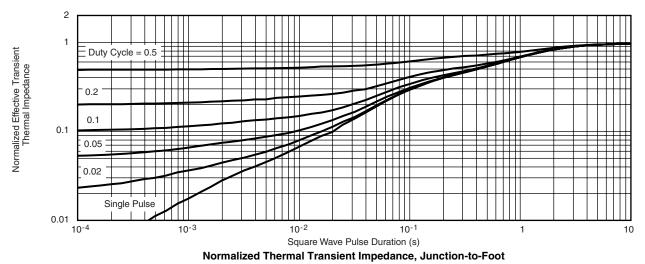




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Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg271234.



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